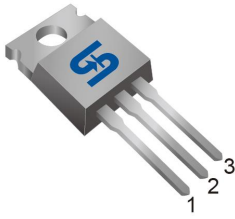


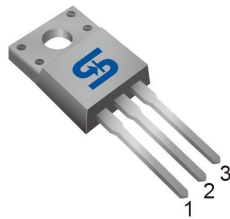
TSM480P06

60V P-Channel Power MOSFET

TO-220



ITO-220



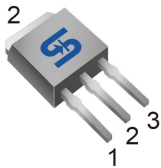
Pin Definition:

1. Gate
2. Drain
3. Source

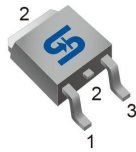
Key Parameter Performance

Parameter	Value	Unit
V_{DS}	-60	V
$R_{DS(on)}$ (max)	$V_{GS} = -10V$	48
	$V_{GS} = -4.5V$	65
Q_g	22.4	nC

TO-251S
(IPAK)



TO-252
(DPAK)

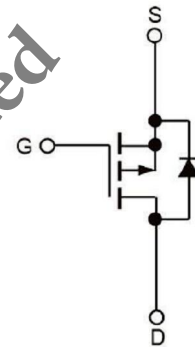


Ordering Information

Part No.	Package	Packing
TSM480P06CZ C0G	TO-220	50pcs / Tube
TSM480P06CI C0G	ITO-220	50pcs / Tube
TSM480P06CH X0G	TO-251S	75pcs / Tube
TSM480P06CP ROG	TO-252	2.5kpcs / 130Reel

Note: C0G denotes for Halogen- and Antimony-free as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds

Block Diagram



P-Channel MOSFET

Absolute Maximum Ratings (Tc = 25°C unless otherwise noted)

Parameter	Symbol	Limit			Unit
		IPAK/DPAK	ITO-220	TO-220	
Drain-Source Voltage	V_{DS}	-60			V
Gate-Source Voltage	V_{GS}	± 20			V
Continuous Drain Current (Note 1)	I_D	$T_C = 25^\circ C$			A
		$T_C = 100^\circ C$			A
Pulsed Drain Current (Note 2)	I_{DM}	-64			A
Single Pulse Avalanche Energy (Note 3)	E_{AS}	51			mJ
Single Pulse Avalanche Current (Note 2)	I_{AS}	-32			A
Power Dissipation @ $T_C = 25^\circ C$	P_D	40	27	66	W
Operating Junction Temperature	T_J	-50 to +150			$^\circ C$
Storage Temperature Range	T_{STG}	-50 to +150			$^\circ C$

Thermal Performance

Parameter	Symbol	Limit			Unit
		IPAK/DPAK	ITO-220	TO-220	
Thermal Resistance - Junction to Case	$R_{\theta JC}$	3.1	4.7	1.9	°C/W
Thermal Resistance - Junction to Ambient	$R_{\theta JA}$	62			°C/W

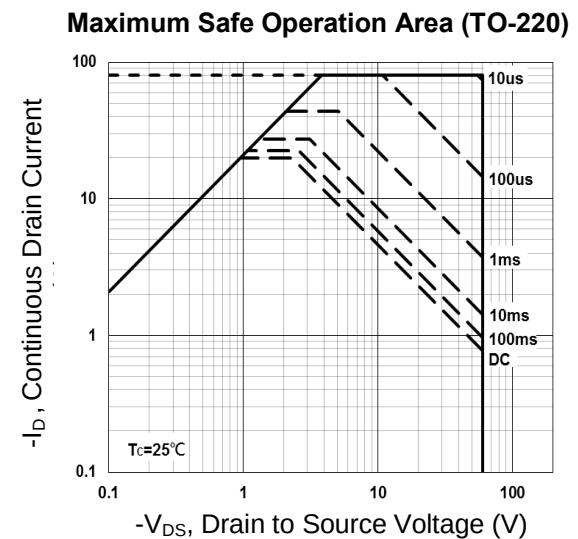
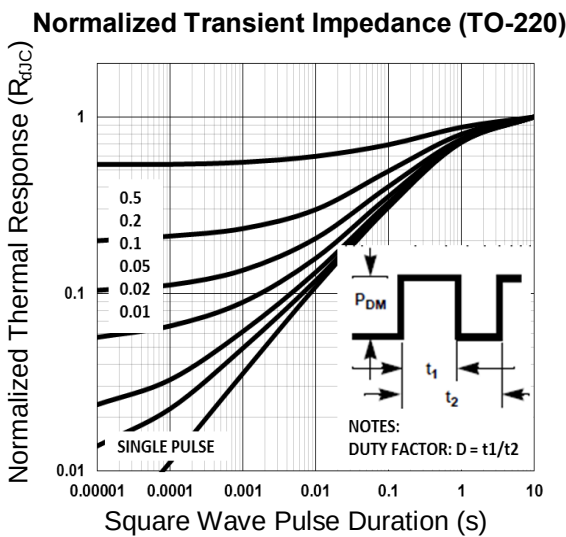
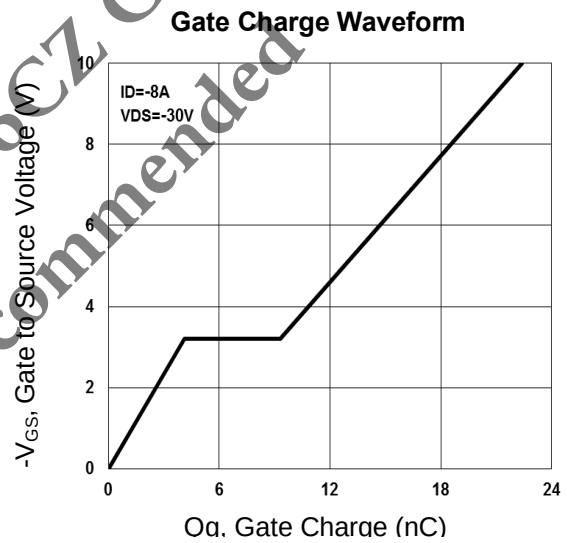
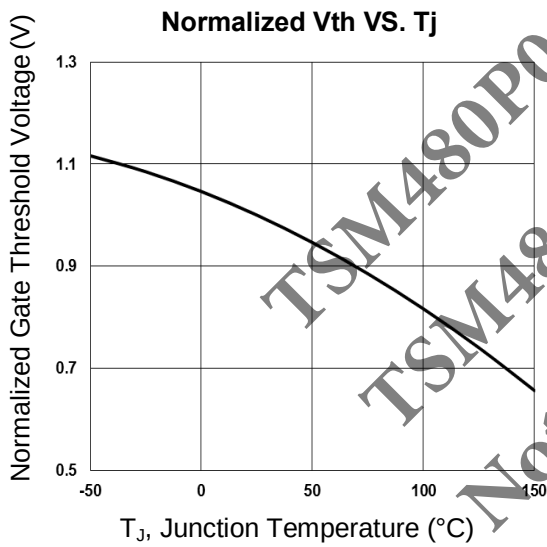
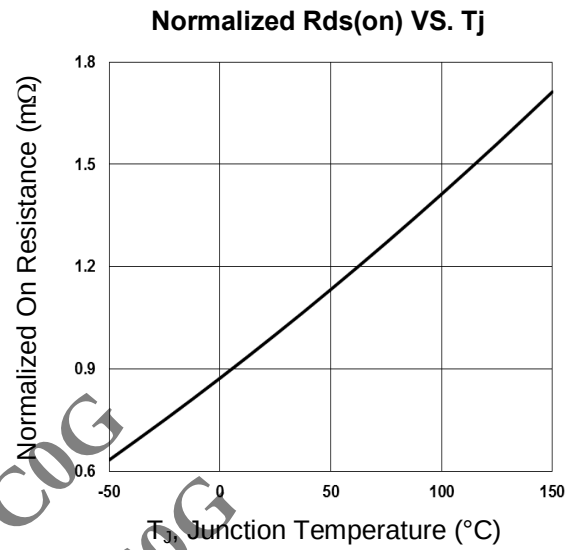
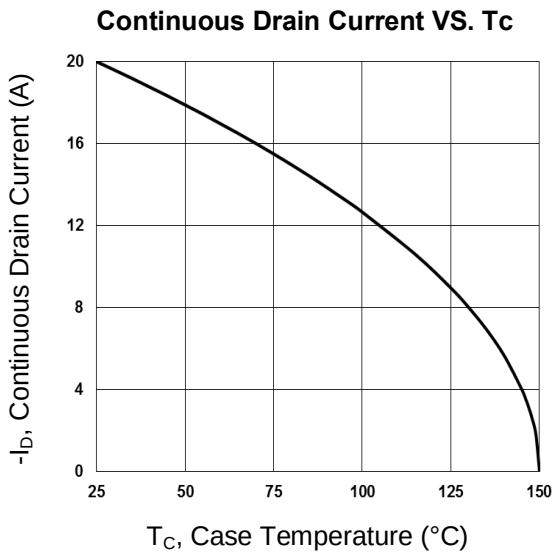
Electrical Specifications ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	BV_{DSS}	-60	--	--	V
Drain-Source On-State Resistance	$V_{GS} = -10V, I_D = -8A$	$R_{DS(ON)}$	--	39	48	mq
	$V_{GS} = -4.5V, I_D = -4A$		--	53	65	
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = -250\mu A$	$V_{GS(TH)}$	-1.2	-1.6	-2.2	V
Zero Gate Voltage Drain Current	$V_{DS} = -60V, V_{GS} = 0V$	I_{DSS}	--	--	-1	μA
	$V_{DS} = -48V, T_C = 125^{\circ}C$		--	--	-10	
Gate Body Leakage	$V_{GS} = \pm 20V, V_{DS} = 0V$	I_{GSS}	--	--	± 100	nA
Forward Transconductance (Note 4)	$V_{DS} = -10V, I_D = -8A$	g_{fs}	--	10	--	S
Dynamic						
Total Gate Charge (Note 4,5)	$V_{DS} = -30V, I_D = -8A,$ $V_{GS} = -10V$	Q_g	--	22.4	--	nC
Gate-Source Charge (Note 4,5)		Q_{gs}	--	4.1	--	
Gate-Drain Charge (Note 4,5)		Q_{gd}	--	5.2	--	
Input Capacitance	$V_{DS} = -30V, V_{GS} = 0V,$ $f = 1.0MHz$	C_{iss}	--	1250	--	pF
Output Capacitance		C_{oss}	--	85	--	
Reverse Transfer Capacitance		C_{rss}	--	65	--	
Switching						
Turn-On Delay Time (Note 4,5)	$V_{DD} = -30V, I_D = -1A,$ $R_{GEN} = 6q$	$t_{d(on)}$	--	13	--	ns
Turn-On Rise Time (Note 4,5)		t_r	--	42.4	--	
Turn-Off Delay Time (Note 4,5)		$t_{d(off)}$	--	64.6	--	
Turn-Off Fall Time (Note 4,5)		t_f	--	16.4	--	
Source-Drain Diode Ratings and Characteristic						
Maximum Continuous Drain-Source Diode Forward Current	Integral reverse diode in the MOSFET	I_S	--	--	-16	A
Maximum Pulse Drain-Source Diode Forward Current		I_{SM}	--	--	-64	A
Diode-Source Forward Voltage	$V_{GS} = 0V, I_S = -1A$	V_{SD}	--	--	-1	V

Note:

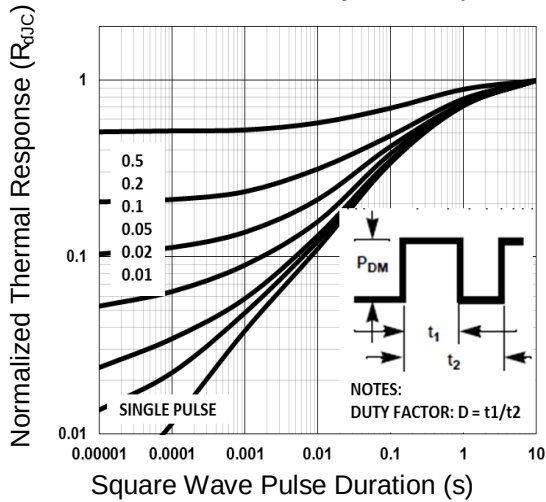
- Limited by maximum junction temperature
- Pulse width limited by safe operating area
- $L = 3.68\text{mH}, I_{AS} = 8A, V_{DD} = 50V, R_G = 25\Omega$, Starting $T_J = 25^\circ\text{C}$
- Pulse test: pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$
- Switching time is essentially independent of operating temperature

Electrical Characteristics Curve

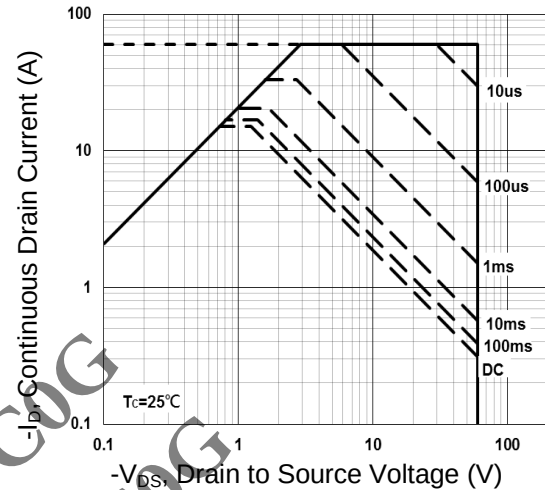


Electrical Characteristics Curve

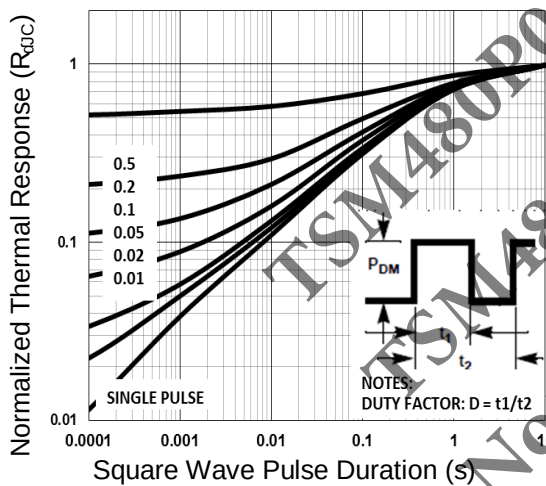
Normalized Transient Impedance (ITO-220)



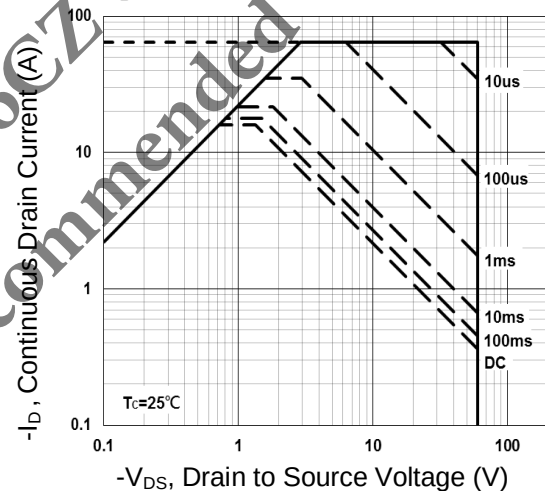
Maximum Safe Operation Area (ITO-220)



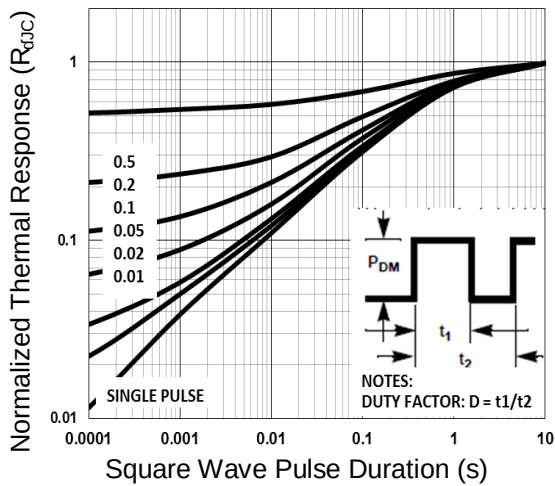
Normalized Transient Impedance (TO-251S)



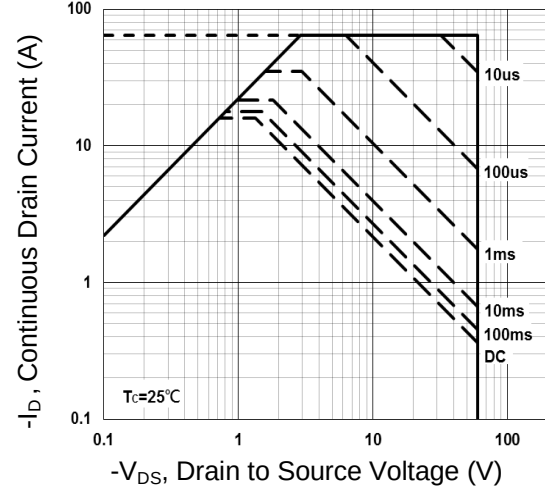
Maximum Safe Operation Area (TO-251S)



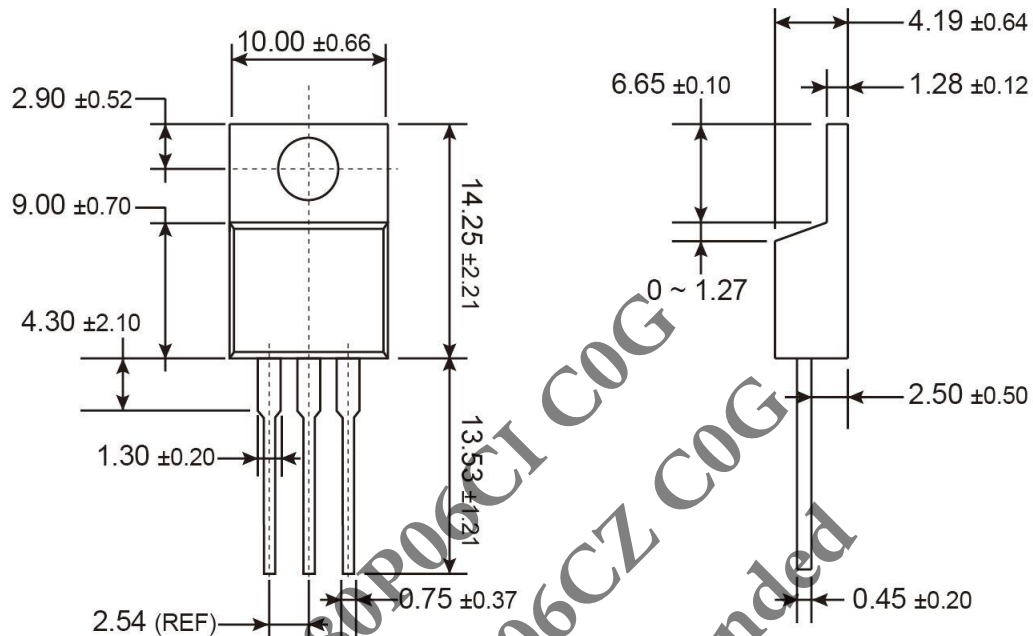
Normalized Transient Impedance (TO-252)



Maximum Safe Operation Area (TO-252)

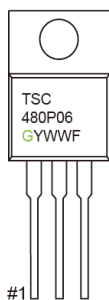


TO-220 Mechanical Drawing



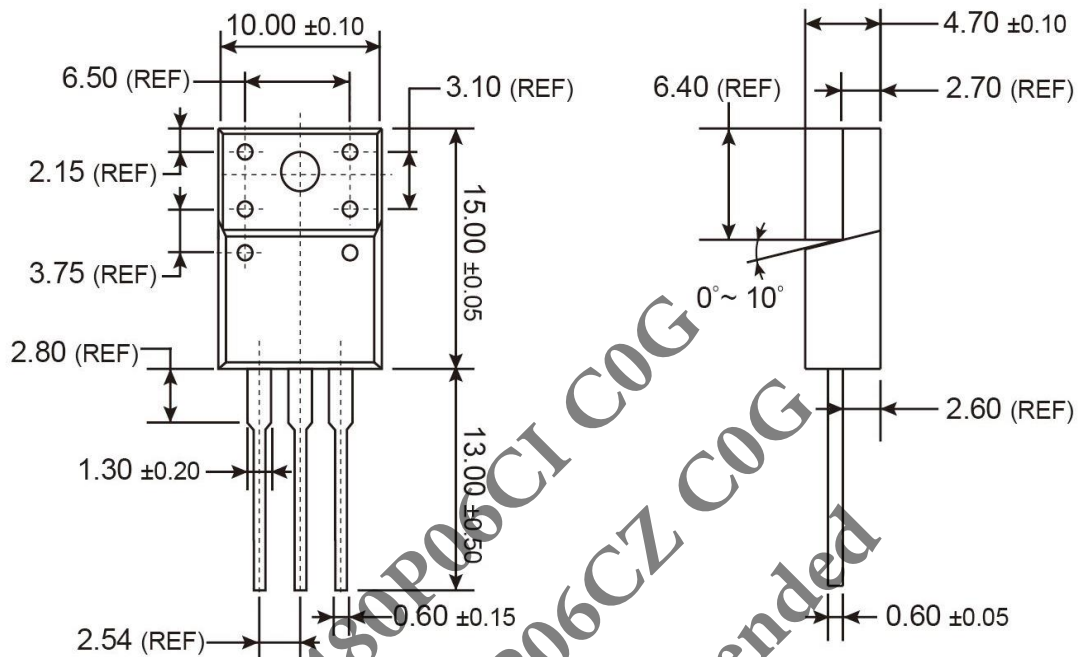
Unit: Millimeters

Marking Diagram



- G** = Halogen Free
- Y** = Year Code
- WW** = Week Code (01~52)
- F** = Factory Code

ITO-220 Mechanical Drawing



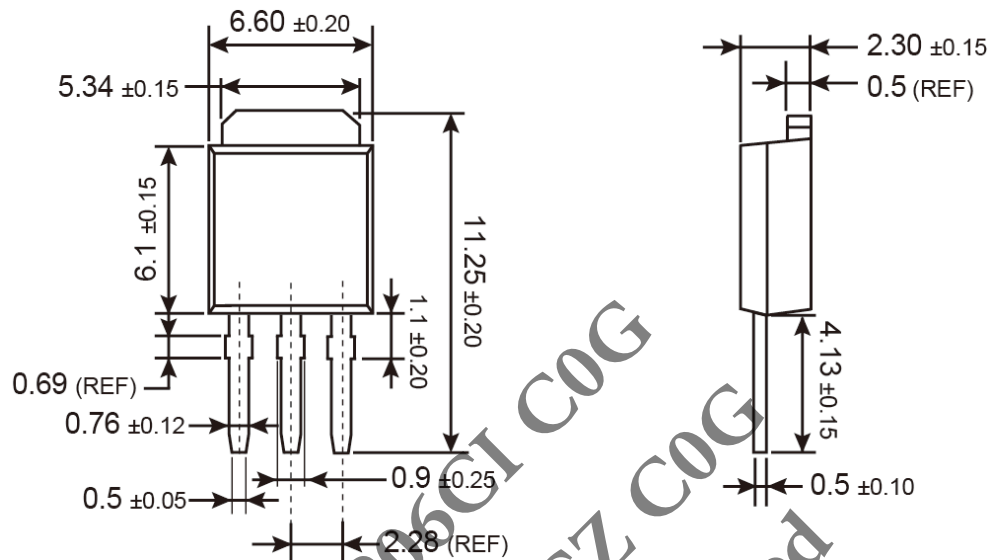
Unit: Millimeters

Marking Diagram



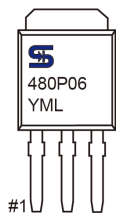
G = Halogen Free
Y = Year Code
WW = Week Code (01~52)
F = Factory Code

TO-251S Mechanical Drawing



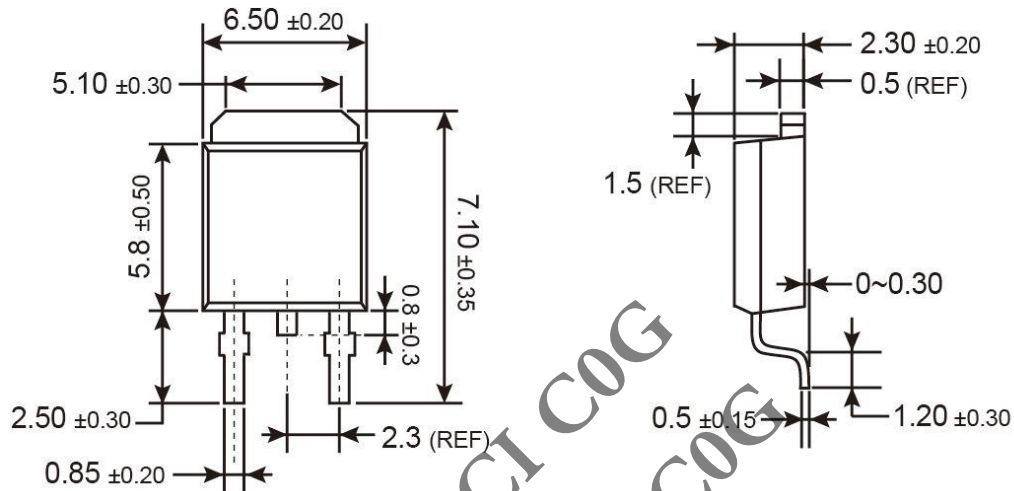
Unit: Millimeters

Marking Diagram



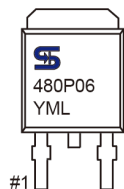
- Y** = Year Code
- M** = Month Code for Halogen Free Product
(**O**=Jan, **P**=Feb, **Q**=Mar, **R**=Apr, **S**=May, **T**=Jun, **U**=Jul, **V**=Aug, **W**=Sep, **X**=Oct, **Y**=Nov, **Z**=Dec)
- L** = Lot Code

TO-252 Mechanical Drawing



Unit: Millimeters

Marking Diagram



Y = Year Code

M = Month Code for Halogen Free Product

(**Q**=Jan, **P**=Feb, **Q**=Mar, **R**=Apr, **S**=May, **T**=Jun, **U**=Jul, **V**=Aug, **W**=Sep, **X**=Oct, **Y**=Nov, **Z**=Dec)

L = Lot Code

TSM480P06

60V P-Channel Power MOSFET

TSM480P06CI C0G
TSM480P06CZ C0G
Not Recommended

Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.



**Стандарт
Электрон
Связь**

Мы молодая и активно развивающаяся компания в области поставок электронных компонентов. Мы поставляем электронные компоненты отечественного и импортного производства напрямую от производителей и с крупнейших складов мира.

Благодаря сотрудничеству с мировыми поставщиками мы осуществляем комплексные и плановые поставки широчайшего спектра электронных компонентов.

Собственная эффективная логистика и склад в обеспечивает надежную поставку продукции в точно указанные сроки по всей России.

Мы осуществляем техническую поддержку нашим клиентам и предпродажную проверку качества продукции. На все поставляемые продукты мы предоставляем гарантию .

Осуществляем поставки продукции под контролем ВП МО РФ на предприятия военно-промышленного комплекса России , а также работаем в рамках 275 ФЗ с открытием отдельных счетов в уполномоченном банке. Система менеджмента качества компании соответствует требованиям ГОСТ ISO 9001.

Минимальные сроки поставки, гибкие цены, неограниченный ассортимент и индивидуальный подход к клиентам являются основой для выстраивания долгосрочного и эффективного сотрудничества с предприятиями радиоэлектронной промышленности, предприятиями ВПК и научно-исследовательскими институтами России.

С нами вы становитесь еще успешнее!

Наши контакты:

Телефон: +7 812 627 14 35

Электронная почта: sales@st-electron.ru

Адрес: 198099, Санкт-Петербург,
Промышленная ул, дом № 19, литера Н,
помещение 100-Н Офис 331